

Product Qualification Report

IMW65R030M1H

SILICON CARBIDE MOSFET

Description

This product qualification report describes the characteristics of the product with respect to quality and reliability.

The qualification sample selection was done on production lots which were manufactured and tested on standard production processes and meet the defined requirements.

The qualification test results of those products as outlined in this document are based on **JEDEC** for target applications and may reference existing qualification results of similar products. Such referencing is justified by the structural similarity of the products.

Qualification Assessment

Fully qualified according to **JEDEC** for **Industrial Applications** and assessed as PASS

For further information about comparable products, please contact the nearest Infineon Technologies office (www.infineon.com).

qualified 2020

IMW65R030M1H
PG-TO247-3
MSL: not applicable

Electrical Stress Test Results:

Test Description	Abbr.	Condition	Duration	Lots/SS	Fail/Qty	Result
High Temperature Reverse Bias JESD22 A108	HTRB*	Ta = 175°C ** V _R = 80% V _{R,max}	1000 h	3 x 77	0 / 231	PASS
High Humidity High Temperature Reverse Bias JESD22 A101	H3TRB*	Ta = 85°C RH = 85% V _R = 80% V _{R,max}	1000 h	3 x 77	0 / 231	PASS
Highly Accelerated Stress Test JESD22 A110	HAST*	Ta = 130°C RH = 85% V _R = 100V	96 h	3 x 77	0 / 231	PASS
High Temperature Gate stress JESD22 A108	HTGS*	Ta = 175°C V _{GS} = ±20 V	1000 h	3 x 77	0 / 231	PASS
Intermittent Operational Life Test MIL-STD 750 / Meth.1037	IOL*	Delta T = 100K	15000 cyc.	3 x 77	0 / 231	PASS
ESD (HBM) JESD22-A114	HBM	1C (1000 V to < 2000 V)				PASS
ESD (CDM) JESD22-C101	CDM	C3 (> 1000 V)				PASS

Environmental Stress Test Results:

Test Description	Abbr.	Condition	Duration	Lots	Fail/Qty	Result
Temperature Cycling JESD22 A104	TC*	-55°C to +150°C	1000 cyc.	3 x 77	0 / 231	PASS
Unbiased Highly Accelerated Stress Test JESD22 A118	UHASt*	Ta = 130°C RH = 85%	96 h	3 x 77	0 / 231	PASS

Mechanical Stress Test Results:

Test Description	Abbr.	Condition	Duration	Lots	Fail/Qty	Result
Destructive Physical Analysis	DPA	samples from UHASt & TC		3	0 / 3	PASS

Notes:

* For SMD devices reliability stress tests are performed after preconditioning test (PC) according to JESD22

** Specifically used stress temperature is according to product capability documented in the product datasheet

Trademarks

All referenced product or service names and trademarks are the property of their respective owners.

Published by
Infineon Technologies AG
81726 München, Germany

© 2022 Infineon Technologies AG.
All Rights Reserved.

Do you have a question about this document?

Email: erratum@infineon.com

Document reference

n.a.

IMPORTANT NOTICE

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffenheitsgarantie").

With respect to any examples, hints or any typical values stated herein and/or any information regarding the application of the product, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

In addition, any information given in this document is subject to customer's compliance with its obligations stated in this document and any applicable legal requirements, norms and standards concerning customer's products and any use of the product of Infineon Technologies in customer's applications.

The data contained in this document is exclusively intended for technically trained staff. It is the responsibility of customer's technical departments to evaluate the suitability of the product for the intended application and the completeness of the product information given in this document with respect to such application.

For further information on the product, technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies office (www.infineon.com).

WARNINGS

Due to technical requirements products may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies office.

Except as otherwise explicitly approved by Infineon Technologies in a written document signed by authorized representatives of Infineon Technologies, Infineon Technologies' products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury.